EMICRO/SIM 2013

XV Escola de Microeletrônica Sul / 28° Simpósio Sul de Microeletrônica Porto Alegre, 29 de abril a 3 de maio de 2013

Simultaneous Gate Sizing and Vth Assignment using Lagrangian Relaxation and Delay Sensitivities

<u>Guilherme Flach</u>, Tiago Reimann, Gracieli Posser Marcelo Johann, Ricardo Reis



PROGRAMA DE

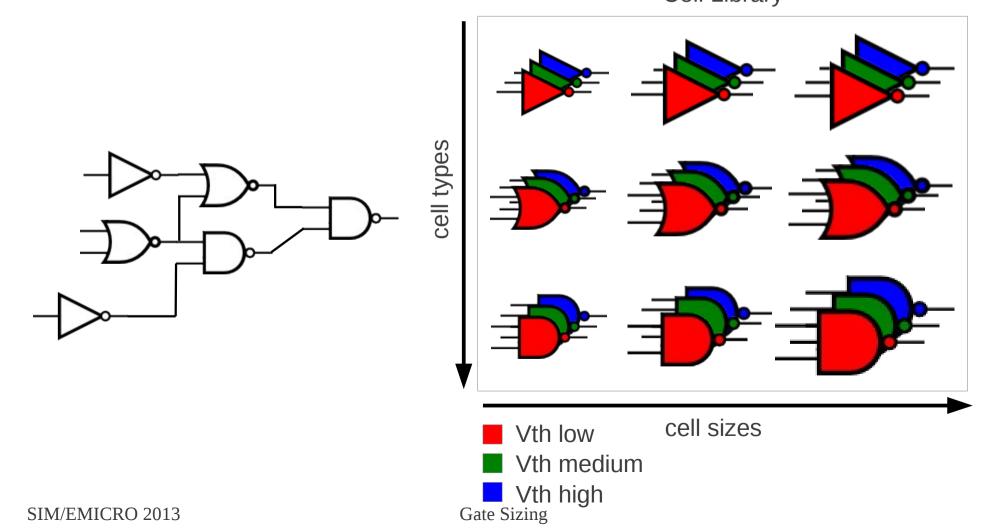
PÓS-GRADUAÇÃO EM MICROELETRÔNICA

SIM/EMICRO 2013 Gate Sizing

What is gate sizing?

Commonly a digital circuit is assembled using standard cells from a library.

Cell Library



What is gate sizing?

Circuit description is then mapped to this library.

Cell Library cell types cell sizes Vth low Vth medium Vth high **Gate Sizing** SIM/EMICRO 2013

What is gate sizing?

 Is the proper selection of gate types in order to trade-off power and timing requirements.

Power → Minimized Frequency → Met

 $min \quad Power(x)$ $s.t. \quad Timing(x) \leq T$

Power → Minimized Frequency → Met

 $min \quad Timing(x)$ s.t. $Power(x) \leq P$

where *x* is the vector with the selected cell type for each cell

Gate Sizing

Discrete

- Also known as gate selection
- NP-Complete
- No exact solution can be found in reasonable time (general case)

Continuous

 Optimum solutions can be found in feasible time but relying on simplified delay models.

Problem Formulation – ISPD Contest 2012

$$min$$
 $Leakage(x)$ $s.t.$ $Timing(x) \leq T$

ISPD Contest 2013

International Symposium on Physical Design

- Static power (leakage) is the main concern.
- Static Timing Analysis used as measure.
- Simplified wire model: lumped capacitance.

Leakage Power

Power consumption when circuit is on but not "working". Gets worse as dimensions shrinks

Lagrangian Relaxation

$$min$$
 $Leakage(x)$ $s.t.$ $Timing(x) \leq T$

Very hard to be solved!

Lagrangian Relaxation

Hard constraints become part of the objective function.

A little bit easier... heuristics still needed.

Problem Formulation – KKT Conditions

Due to KKT conditions to optimality, we got...

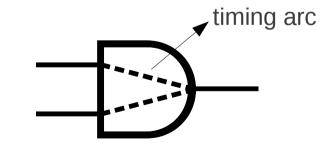
$$min \ Leakage(x) + \lambda(Timing(x) - T)$$

quivalent

C. P. Chen, C. C.-N. Chu, and D. F. Wong Fast and exact simultaneous gate and wire sizing by lagrangian relaxation

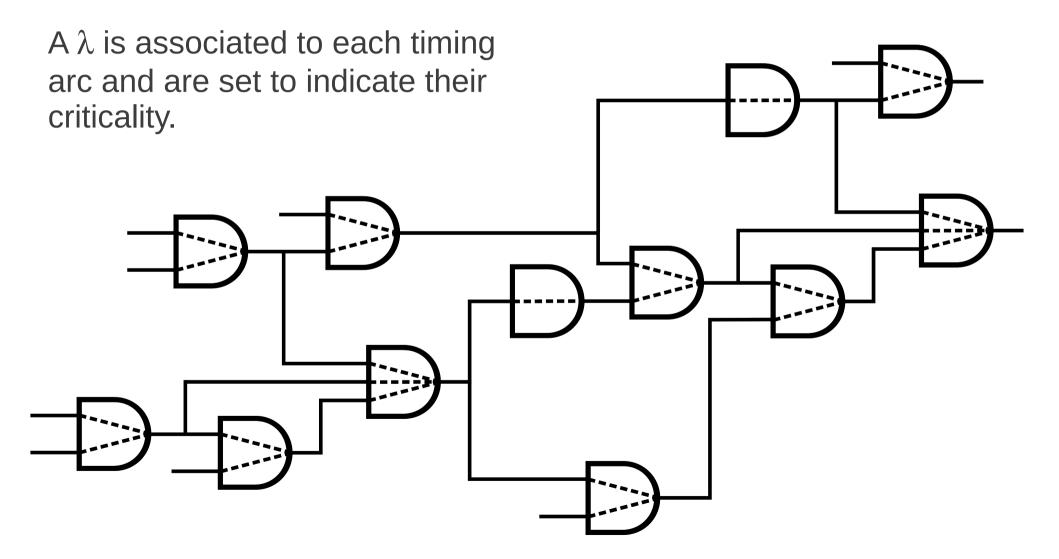
IEEE Trans. on Computer-Aided Design

 $\min \ \ Leakage(x) + \lambda delay_k$ where delay, is the delay of timing ark k



Problem Formulation - After All

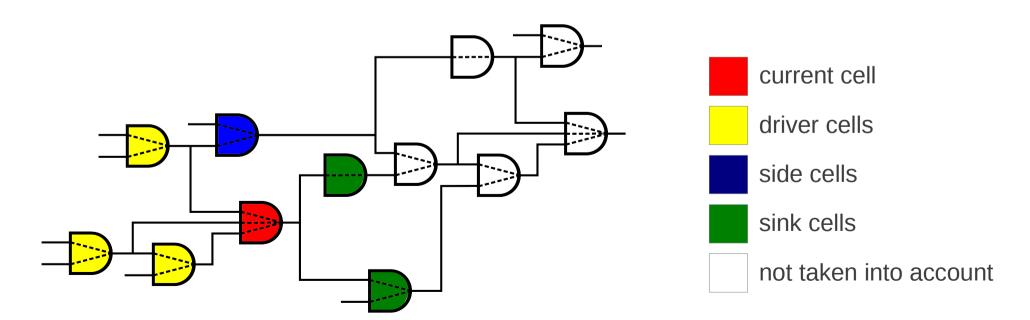
 $min \ Leakage(x) + \lambda delay_k$



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Approach

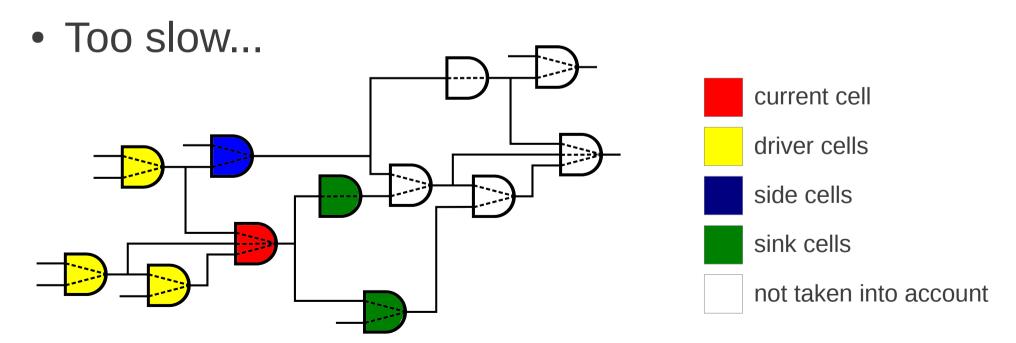
- min $Leakage(x) + \lambda delay_k$
- for each cell in topological order
 - try every cell type and chose the one which locally best trades-off leakage and delay.



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Why only local effects are taken into account?

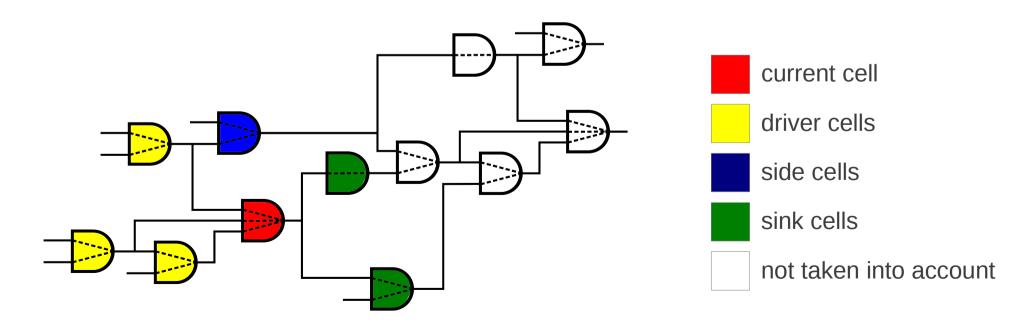
- Well, a change in a cell type may affect several timing arc delays.
- But an incremental STA would be required for each cell change to keep timing updated.



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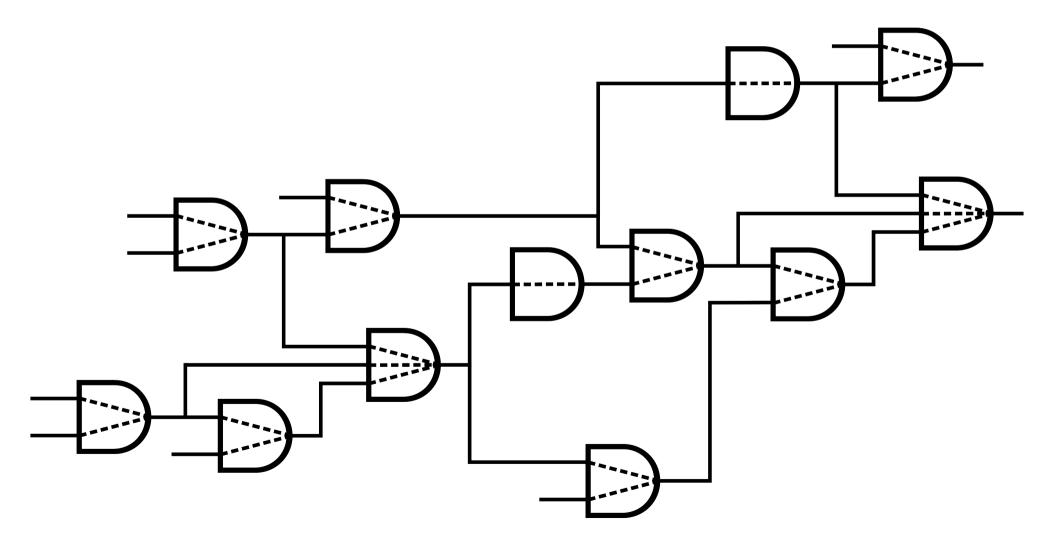
But isn't that too bad?

 Not totally, since the most effect occurs on the first levels.

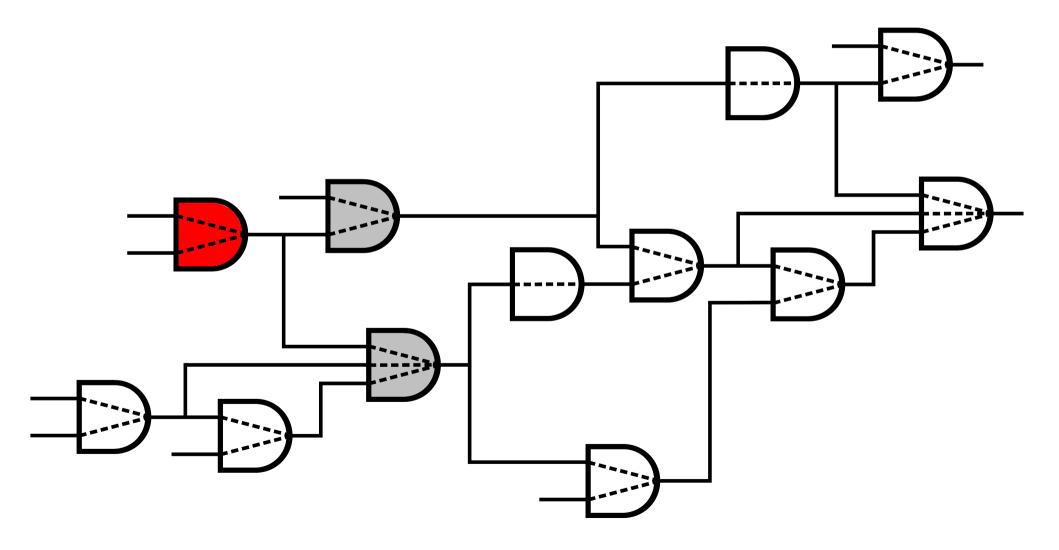


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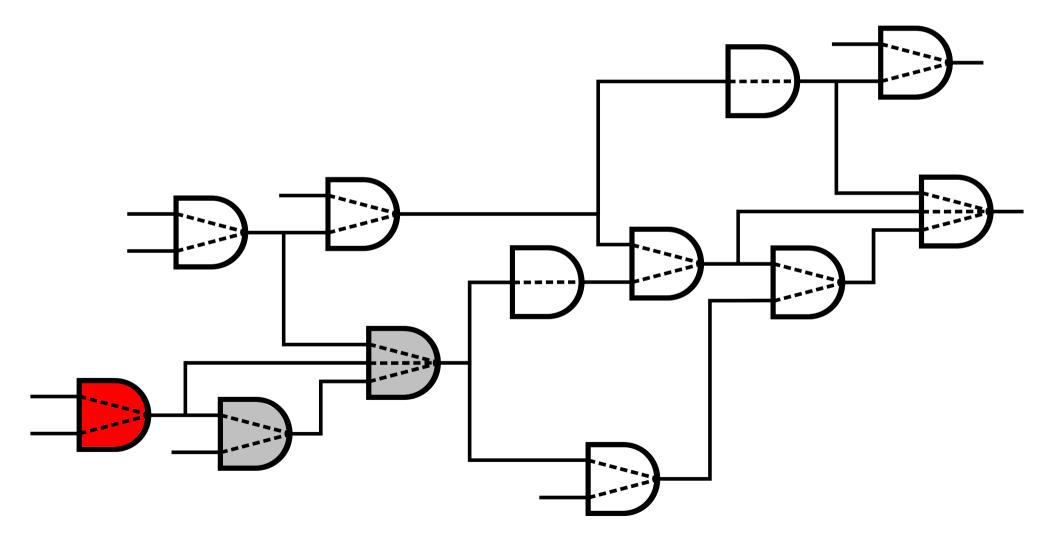
Greedy Algorithm



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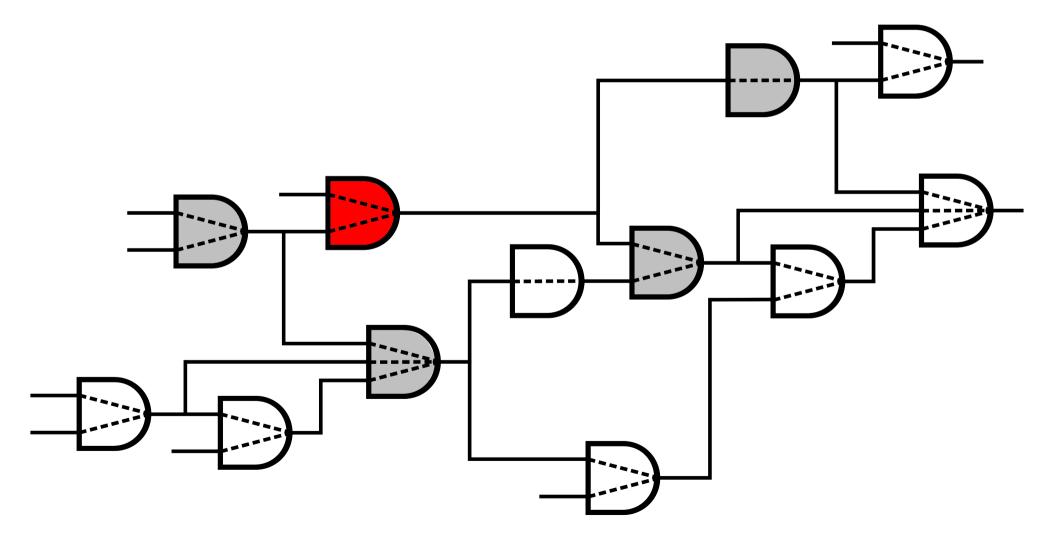


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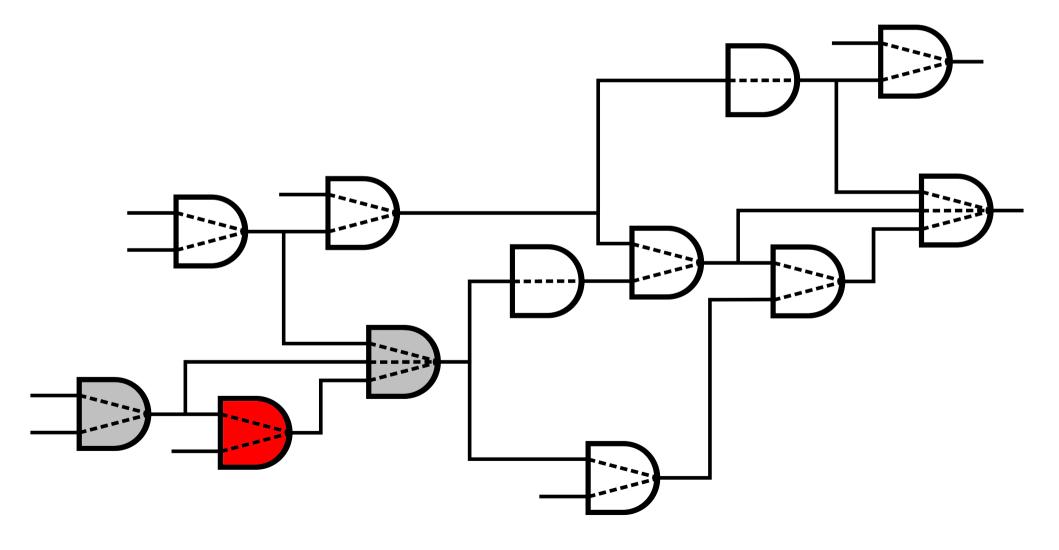
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Greedy Algorithm



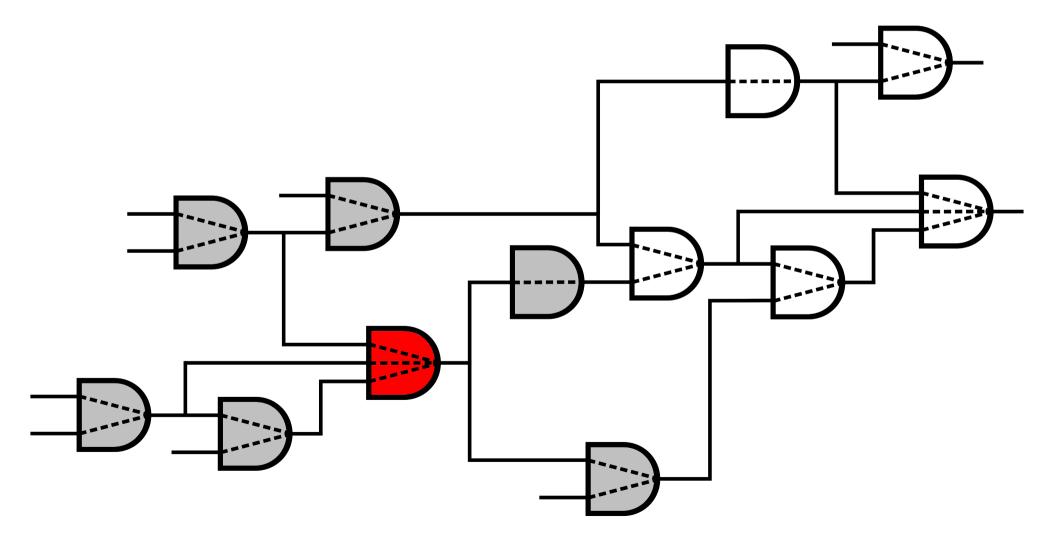
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Greedy Algorithm



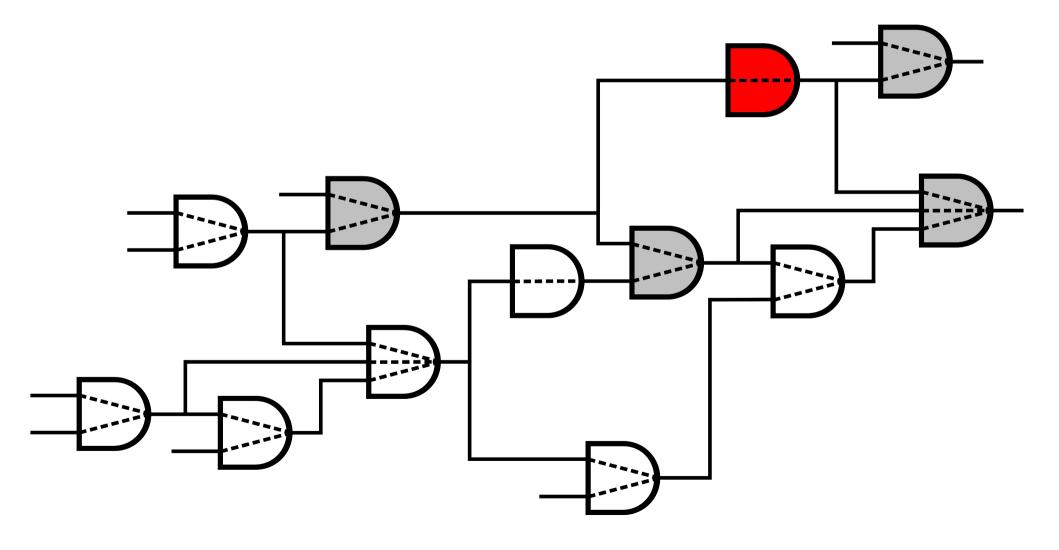
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Greedy Algoritm



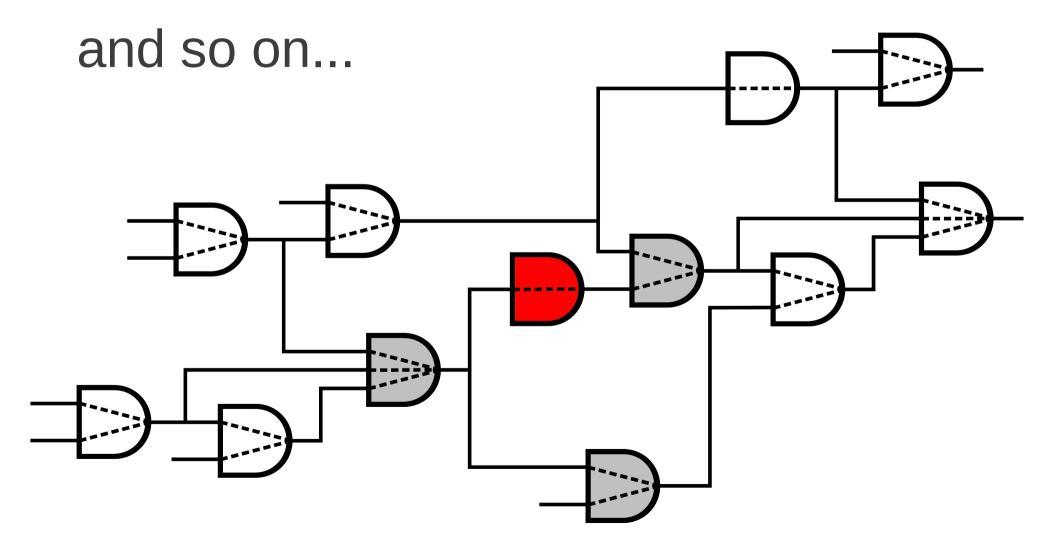
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Greedy Algorithm



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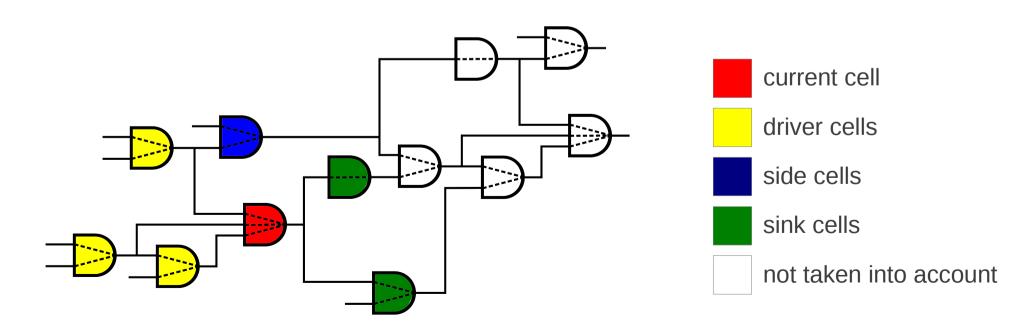
Greedy Algorithm



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Can we do better?

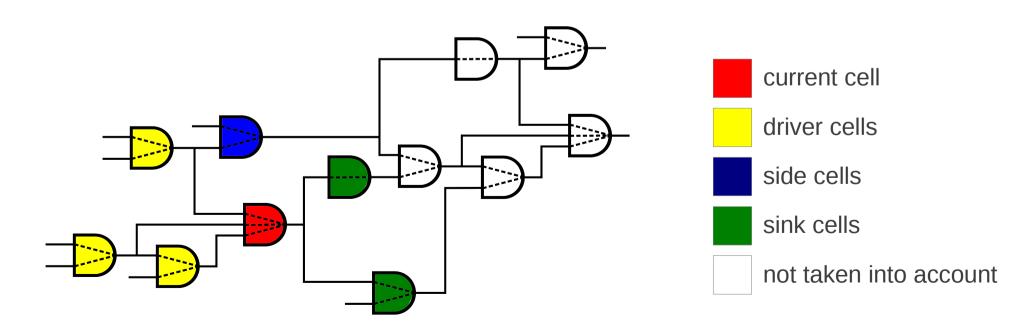
- Dealing with the cells other than that in the vicinity.
- Propagate back the timing arc delays sensitivities.



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Timing Arc Delay Sensitivities

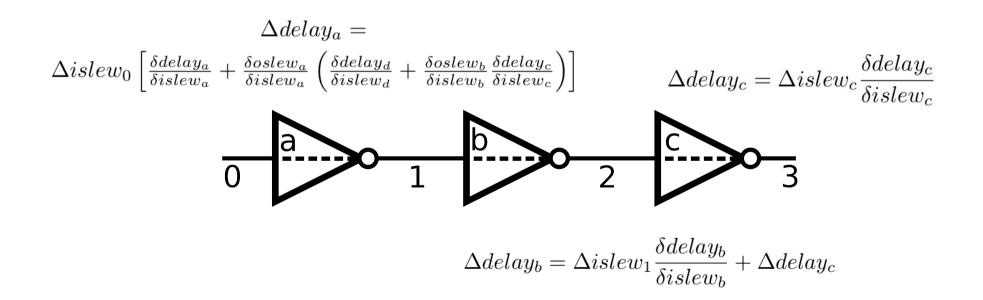
- Idea: how a change in the middle of circuit affect the overall circuit time
 - without requiring to execute STA



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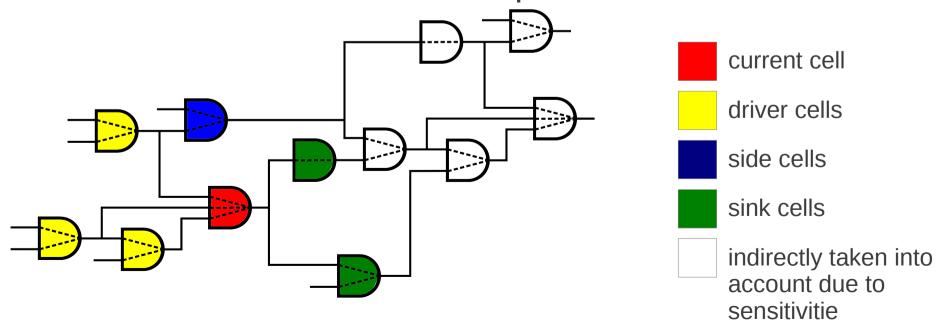
Timing Arc Delay Sensitivities

- for timing arc in reverse topological order
 - compute and propagate its sensitivity in delay due to a change in its input slew



Timing Arc Delay Sensitivities

- Precise timing information is still only locally computed...
 - but sensitivities provides a way to see what may happen globally;
 - an no incremental STA required.



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Power and Timing Recovery

- After selecting cells via Lagrangian:
 - sweep all cells trying to fix any timing violation left
 - usually our Lagrangian model provides a small timing violation
 - sweep all cells trying to decrease leakage power
- In these methods, an incremental STA is used for each cell change.

Results

- Smallest leakage power for every ISPD 2012 benchmark.
 - 23k cells circuit sized in less than 1min.
 - 861K cells circuit sized in less than 50min.

	# of	Leakage Power (W)			Power Saved (%)		Runtime (m)			OurLPRS Reduction (%)	
Benchmark	Comb.	Hu	Li	Our-	Compared	Compared	Hu	Li	Our-	Compared	Compared
	Cells	[1]	[2]	LPRS	to [1]	to [2]	[1]	[2]	LPRS	to [1]	to [2]
DMA_slow	23K	0.145	0.153	0.132	8.73	13.50	9.90	0.60	0.79	92.02	-31.67
DMA_fast		0.299	0.281	0.238	20.29	15.19	13.90	0.60	0.92	93.38	-53.33
pci_bridge32_slow	30K	0.111	0.111	0.096	13.31	13.31	10.20	1.20	0.87	91.47	27.50
pci_bridge32_fast		0.183	0.167	0.136	25.51	18.37	13.00	1.20	0.92	92.92	23.33
des_perf_slow	102K	0.614	0.671	0.570	7.14	15.03	70.10	6.00	25.31	63.89	-321.83
des_perf_fast		1.842	1.93	1.395	24.27	27.73	82.70	6.60	16.37	80.21	-148.03
vga_lcd_slow	148K	0.351	0.375	0.328	6.61	12.59	87.50	7.80	5.67	93.52	27.31
vga_lcd_fast		0.471	0.46	0.413	12.22	10.12	45.60	10.20	8.37	81.64	17.94
b19_slow	213K	0.583	0.604	0.564	3.28	6.64	213.90	10.20	9.15	95.72	10.29
b19_fast		0.771	0.784	0.717	7.06	8.61	206.50	12.00	11.75	94.31	2.08
leon3mp_slow	540K	1.341	1.4	1.334	0.53	4.72	1,274.00	43.80	38.98	96.94	11.00
leon3mp_fast		1.487	1.64	1.443	2.99	12.04	1,323.20	54.60	46.62	96.48	14.62
netcard_slow	861K	1.77	1.78	1.763	0.41	0.97	299.90	48.00	34.39	88.53	28.35
netcard_fast		1.861	2.18	1.841	1.07	15.55	1,096.90	88.80	47.41	95.68	46.61
Avg.	-	0.845	0.895	0.784	9.53	12.45	-	-	-	-	-
Sum (h)	-	-	-	-	-	-	79.12	4.86	4.13	94.79	15.12

Conclusions

- Lagrangian Relaxation fits well to model the discrete gate sizing problem.
 - Mainly when simplified by KKT conditions
- A change in a cell type may affect almost the whole circuit.
 - However the most effects are nearby the changed cell.
 - The remaining effect can be estimated propagating back the delay sensitivities of timing arcs.

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